JIEJIE MICROELECTRONICS CO., LTD.

JEER3006ZCT EPI SUPERFAST SOFT RECOVERY RECTIFIER

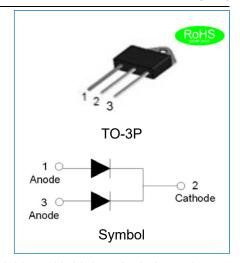
Rev.1.5

DESCRIPTION

- Plastic package has underwriters laboratory flammability classification 94V-0
- ♦ Lead free in comply with EU RoHS 2011/65/EU directives
- ♦ Low reverse leakage current
- ♦ Superfast recovery time and soft recovery characteristics
- ♦ Low recovery loss

MECHANICAL DATA

- ♦ Case: TO-3P molded plastic over passivated junction
- ♦ Terminals: Solder plated, solderable per J-STD-002
- ♦ Internally constructed isolated package is offered for ease of heat sinking with highest isolation voltage
- ♦ Weight:4.805gram



ABSOLUTE MAXIMUM RATING (Rating at 25℃ case temperature unless otherwise specified.)

Parameter	Symbol	JEER3006ZCT	Unit
Maximum repetitive peak reverse voltage	V _{RRM}	600	V
Maximum DC blocking voltage	V _{DC}	600	V
Maximum average forward rectified current at T _{mb} =128℃	I _{F(AV)}	30	Α
Peak forward surge current: 10ms single half sine-wave superimposed on rated load (per diode)	IFSM	140	А
Junction temperature and storage temperature range	T_{j} , T_{stg}	-55 to +150	$^{\circ}\! \mathbb{C}$

ISOLATION CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
		50Hz≤f≤60Hz;RH≤65%;from				
V _{isol(RMS)}	RMS isolation voltage	all pins to external heatsink;	_	-	2500	\/
V isol(RMS)	Trivio isolation voltage	sinusoidal waveform;	-			V
		clean and dust free				
C	la elation conscitance	from cathode to external		10		"F
Cisol	Isolation capacitance	heatsink		10	-	pF



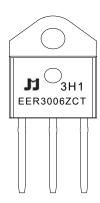
Parameter			Min.	Тур.	Max.	Unit
Forward voltage	IF=15A,Tj=25℃	VF	-	1.4	1.7	V
Forward voltage	IF=15A,Tj=150℃	- VF	-	1.1	1.4	
Reverse current	V _R =600V,T _j =25°C	1-	-	-	5	
Reverse current	V _R =600V,T _j =150℃	IR	1	-	300	μΑ
	I _F =1A, V _R =30V, dI _F /dt=100A/µs, T _j =25℃		-	25	50	
D	I _F =15A, V _R =400V, dI _F /dt=200A/µs, T _j =25℃	t _{rr}	-	45	-	
Reverse recovery time	I _F =15A, V _R =400V, dI _F /dt=200A/µs, T _j =125℃		-	65	-	ns
	I _F =15A, V _R =400V, dI _F /dt=500A/µs, T _j =25℃		-	34	-	
Peak reverse recovery	I _F =15A, V _R =400V, dI _F /dt=200A/µs, T _j =25℃		-	5.5	-	^
current	I _F =15A, V _R =400V, dI _F /dt=200A/µs, T _j =125℃	- I _{RM}	-	9.7	-	А
	I _F =15A, V _R =400V, dI _F /dt=200A/µs, T _j =25℃		-	125	-	· C
Recovered charge	I _F =15A, V _R =400V, dI _F /dt=200A/μs, T _j =125°C	- Qr	-	318		nC

THERMAL RESISTANCES

Symbol	Parameter	Min.	Тур.	Max.	Unit
D	Thermal resistance from junction to mounting base, per diode	-	1.2	2	°C/W
R _{th(j-mb)}	Thermal resistance from junction to mounting base, both diodes conducting	1	0.65	1.2	C/VV
R _{th(j-a)}	Thermal resistance from junction to ambient	-	45	-	°C/W



MARKING



EER	EPI Superfast Recovery Rectifier
30	I _{F(AV)} =30A
06	V _{RRM} : 600V
Z	Package: TO-3P
СТ	Common cathode

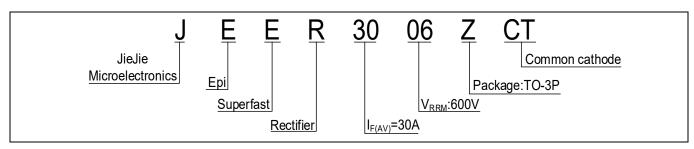
 $\underline{\textbf{x}}\text{H1: Month, 1, 2, 3} \sim \text{9, A, B, C}$

3<u>x</u>1:

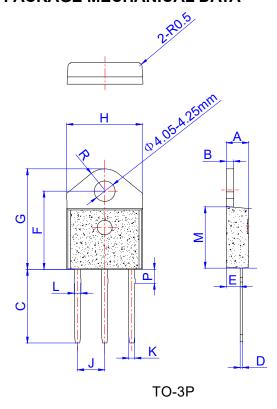
2018	2019	2020	2021	2022	2023	2024
Н	I	J	K	L	М	Ν
2025	2026	2027	2028	2029	2030	
0	Р	Q	R	S	Т	

3Hx: Batch number

ORDERING INFORMATION



PACKAGE MECHANICAL DATA

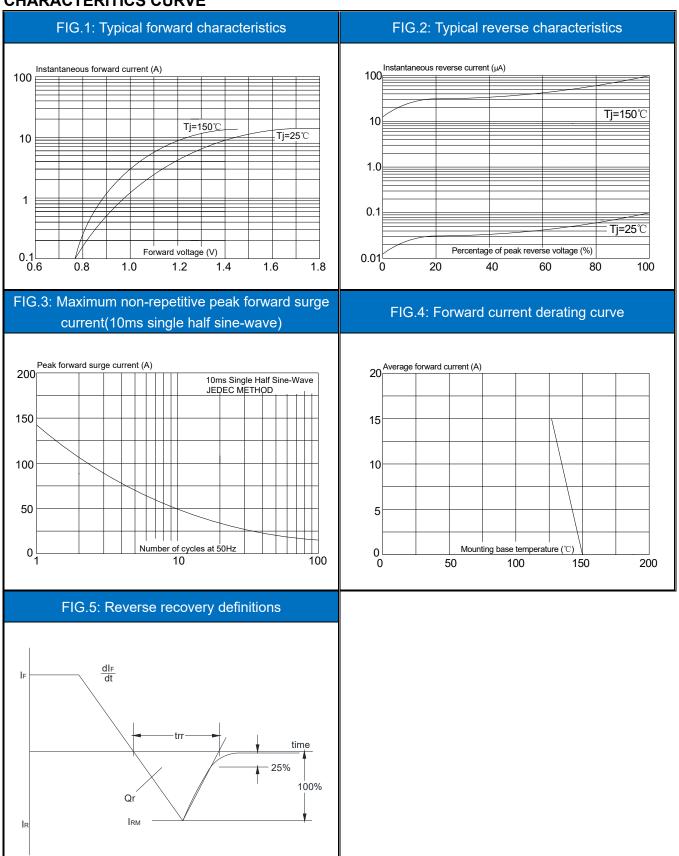


	Dimensions							
Ref.		Millimeters		Inch		Inches		
	Min.	Тур.	Max.	Min.	Тур.	Max.		
Α	4.40		4.60	0.173		0.181		
В	1.45		1.55	0.057		0.061		
С	14.35		15.60	0.565		0.614		
D	0.50		0.70	0.020		0.028		
E	2.70		2.90	0.106		0.114		
F	15.80		16.50	0.622		0.650		
G	20.40		21.10	0.803		0.831		
Н	15.10		15.50	0.594		0.610		
J	5.40		5.65	0.213		0.222		
K	1.10		1.40	0.043		0.055		
L	1.35		1.50	0.053		0.059		
М	12.37		12.77	0.487		0.503		
Р	2.80		3.00	0.110		0.118		
R		4.35			0.171			

PACKAGE INFORMATION-TO-3P

OUTLINE	UNIT WEIGHT (g/PCS) typ.	TUBE (PCS)	PER CARTON (PCS)
TUBE	4.805	30	2,250

CHARACTERITICS CURVE





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